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FAIRCHILD

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SGH15N60RUFD Short Circuit Rated IGBT

General Description

Fairchild's RUFD series of Insulated Gate Bipolar Transistors (IGBTs) provide low conduction and switching losses as well as short circuit ruggedness. The RUFD series is designed for applications such as motor control, uninterrupted power supplies (UPS) and general inverters where short circuit ruggedness is a required feature.

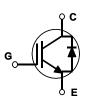
Features

- Short circuit rated 10us @ $T_C = 100^{\circ}C$, $V_{GE} = 15V$
- High speed switching
- Low saturation voltage : $V_{CE(sat)} = 2.2 \text{ V} @ I_C = 15 \text{ A}$
- High input impedance
- CO-PAK, IGBT with FRD : $t_{rr} = 42ns$ (typ.)

Applications

AC & DC motor controls, general purpose inverters, robotics, and servo controls.

G C E TO-3P



Absolute Maximum Ratings T_C = 25°C unless otherwise noted

Symbol	Description		SGH15N60RUFD	Units	
V _{CES}	Collector-Emitter Voltage		600	V	
V _{GES}	Gate-Emitter Voltage		± 20	V	
I _C	Collector Current	@ $T_{C} = 25^{\circ}C$	24	A	
	Collector Current	@ T _C = 100°C	15	A	
I _{CM (1)}	Pulsed Collector Current		45	Α	
I _F	Diode Continuous Forward Current	@ T _C = 100°C	15	A	
I _{FM}	Diode Maximum Forward Current		160	A	
T _{SC}	Short Circuit Withstand Time	@ T _C = 100°C	10	us	
P _D	Maximum Power Dissipation	@ $T_{C} = 25^{\circ}C$	160	W	
	Maximum Power Dissipation	@ T _C = 100°C	64	W	
TJ	Operating Junction Temperature		-55 to +150	°C	
T _{stg}	Storage Temperature Range		-55 to +150	°C	
TL	Maximum Lead Temp, for Soldering		300	°C	

Notes :

(1) Repetitive rating : Pulse width limited by max. junction temperature

Thermal Characteristics

Symbol	Parameter	Тур.	Max.	Units
R _{0JC} (IGBT)	Thermal Resistance, Junction-to-Case		0.77	°C/W
R _{0JC} (DIODE)	Thermal Resistance, Junction-to-Case		0.7	°C/W
R_{\thetaJA}	Thermal Resistance, Junction-to-Ambient		40	°C/W

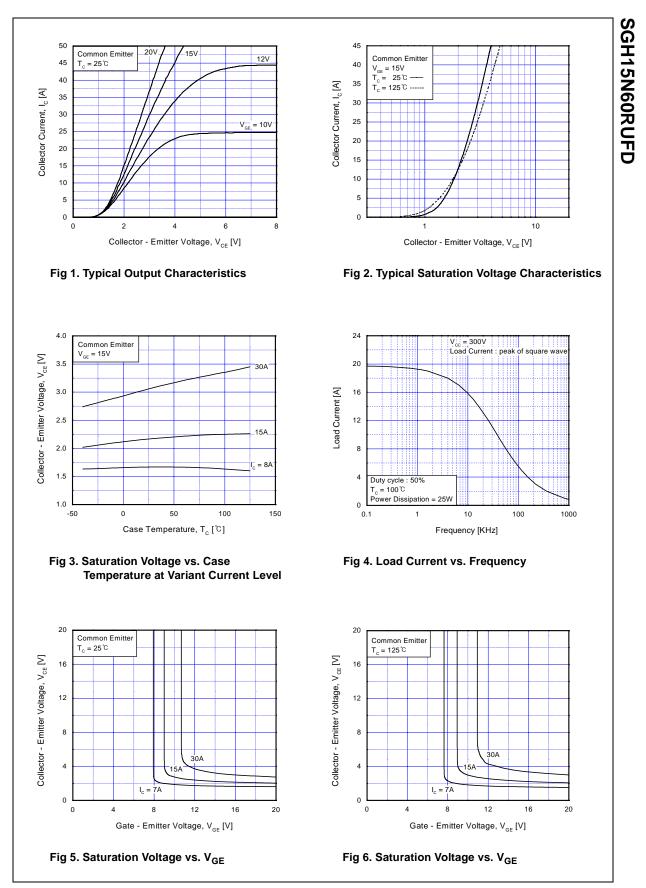
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IGBT

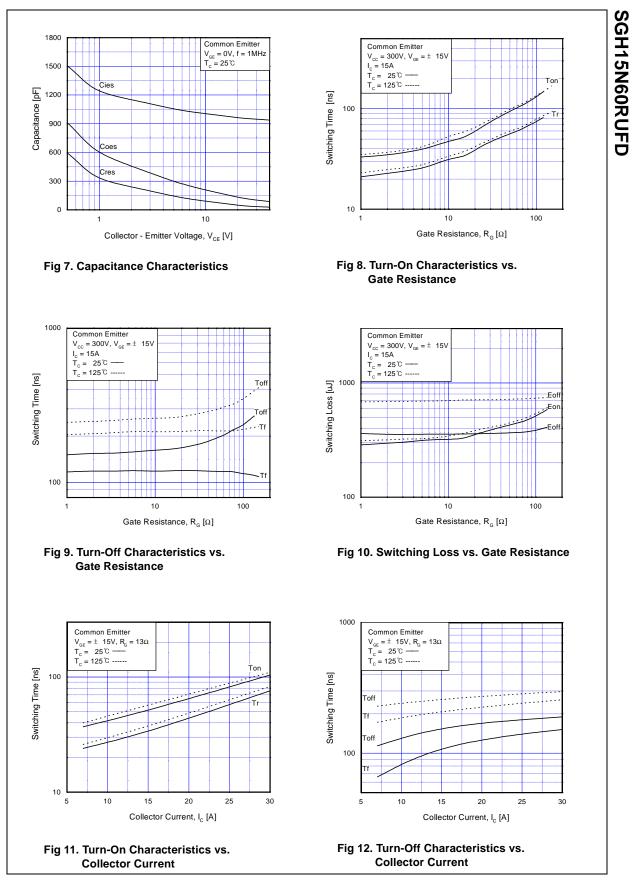
Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Units
Off Char	acteristics					
BV _{CES}	Collector-Emitter Breakdown Voltage	$V_{GE} = 0V, I_{C} = 250uA$	600			V
ΔB _{VCES} / ΔT _J	Temperature Coefficient of Breakdown Voltage	$V_{GE} = 0V, I_C = 1mA$		0.6		V/°C
I _{CES}	Collector Cut-Off Current	$V_{CE} = V_{CES}, V_{GE} = 0V$			250	uA
I _{GES}	G-E Leakage Current	$V_{GE} = V_{GES}, V_{CE} = 0V$			± 100	nA
On Char	acteristics					
	G-E Threshold Voltage	I _C = 15mA, V _{CE} = V _{GE}	5.0	6.0	8.5	V
V _{GE(th)}	Collector to Emitter	$I_{\rm C} = 15 {\rm MA}, V_{\rm CE} = V_{\rm GE}$ $I_{\rm C} = 15 {\rm A}, V_{\rm GE} = 15 {\rm V}$		2.2	2.8	V
V _{CE(sat)}	Saturation Voltage	$I_{\rm C} = 24$ A, $V_{\rm GE} = 15$ V		2.5		v
				2.0		-
Dynamio	Characteristics					
C _{ies}	Input Capacitance	$V_{} = 30V_{} = 0V_{}$		948		pF
C _{oes}	Output Capacitance	V _{CE} = 30V, V _{GE} = 0V, f = 1MHz		101		pF
C _{res}	Reverse Transfer Capacitance	1 - 110112		33		pF
t _{d(on)} t-	Turn-On Delay Time Rise Time	-		17 33		ns ns
<u>t_r</u>	,	-				
t _{d(off)}	Turn-Off Delay Time	V _{CC} = 300 V, I _C = 15A,		44	65	nS
t _f	Fall Time	R _G = 13Ω, V _{GE} = 15V,		118	200	ns
E _{on}	Turn-On Switching Loss	Inductive Load, T _C = 25°C		320		uJ
E _{off}	Turn-Off Switching Loss			356		uJ
E _{ts}	Total Switching Loss			676	950	uJ
t _{d(on)}	Turn-On Delay Time			20		ns
t _r	Rise Time			34		ns
t _{d(off)}	Turn-Off Delay Time	V _{CC} = 300 V, I _C = 15A,		48	70	ns
t _f	Fall Time	$R_G = 13\Omega$, $V_{GE} = 15V$,		212	350	ns
E _{on}	Turn-On Switching Loss	Inductive Load, T _C = 125°C		340		uJ
E _{off}	Turn-Off Switching Loss			695		uJ
E _{ts}	Total Switching Loss			1035	1450	uJ
T _{sc}	Short Circuit Withstand Time	$V_{CC} = 300 \text{ V}, V_{GE} = 15 \text{ V}$ @ T _C = 100°C	10			us
Qg	Total Gate Charge	V _{CE} = 300 V, I _C = 15A,		42	60	nC
Q _{ge}	Gate-Emitter Charge	$V_{CE} = 300 \text{ v}, \text{ I}_{C} = 15\text{A},$ - $V_{GE} = 15\text{V}$		7	10	nC
Q _{gc}	Gate-Collector Charge			17	24	nC
Le	Internal Emitter Inductance	Measured 5mm from PKG		14		nH

Electrical Characteristics of DIODE $T_{C} = 25^{\circ}C$ unless otherwise noted

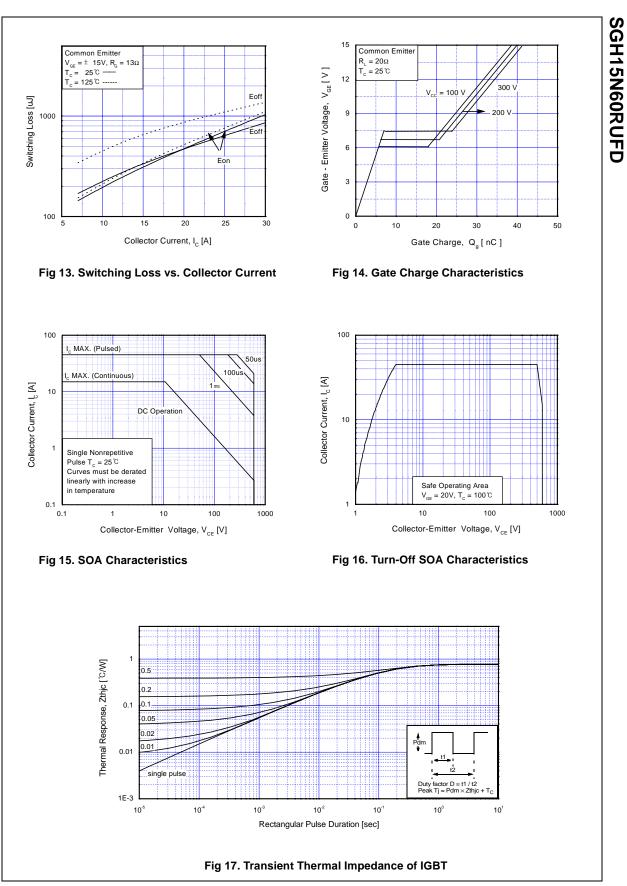
Symbol	Parameter	Test Conditions		Min.	Тур.	Max.	Units
V_{FM}	Diode Forward Voltage	$I_{\Gamma} = 15A$	$T_{C} = 25^{\circ}C$		1.4	1.7	V
			$T_C = 100^{\circ}C$		1.3		
	Diode Reverse Recovery Time		$T_{C} = 25^{\circ}C$		42	60	ns
۲r		I _F = 15A, di/dt=200 A/us	$T_C = 100^{\circ}C$		60		
	Diode Peak Reverse Recovery		$T_{C} = 25^{\circ}C$		3.5	6.0	۸
Irr	Current		T _C = 100°C		5.6		A
0	Diode Reverse Recovery Charge		$T_{C} = 25^{\circ}C$		80	180	nC
Q _{rr}			$T_C = 100^{\circ}C$		220		nc

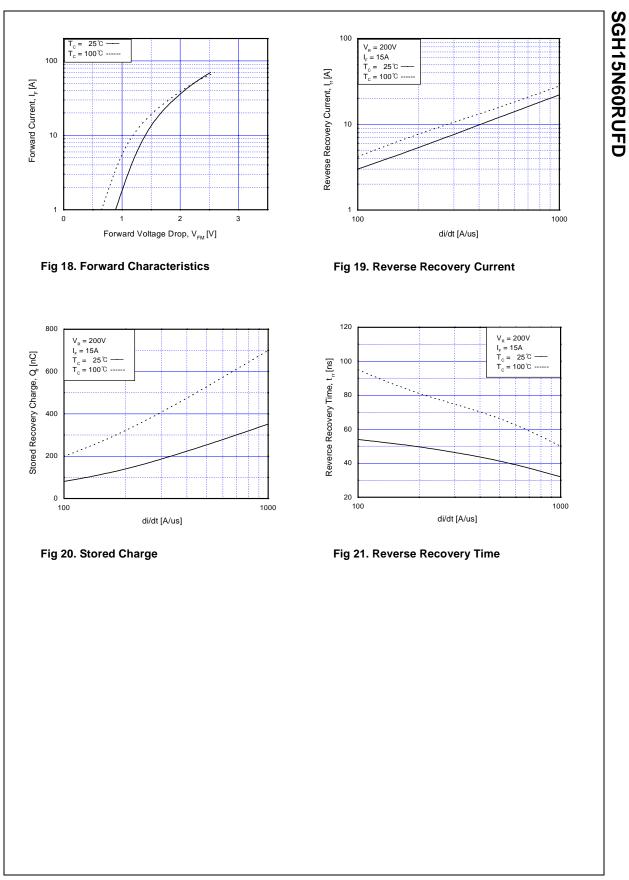


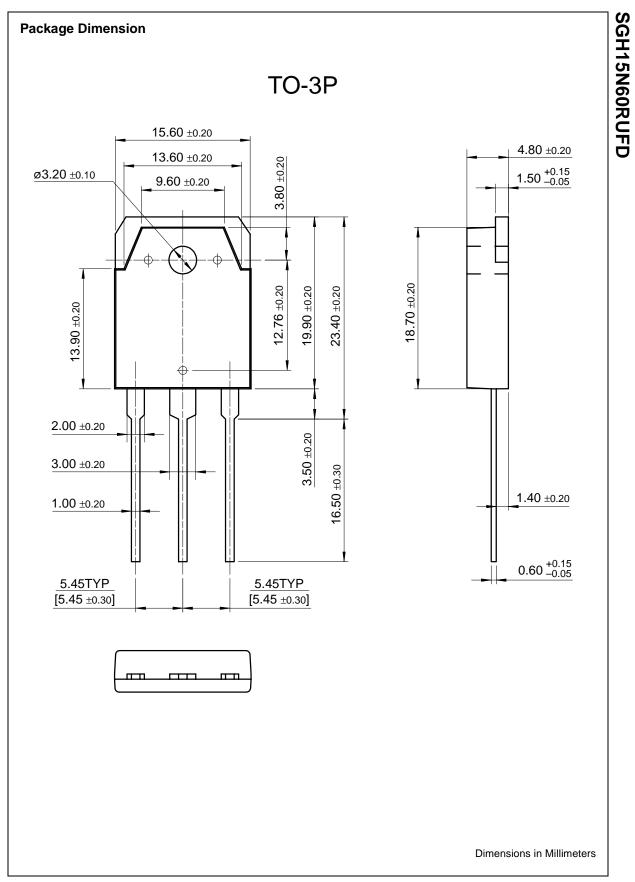
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